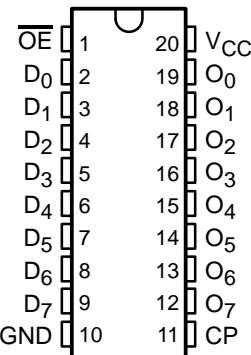
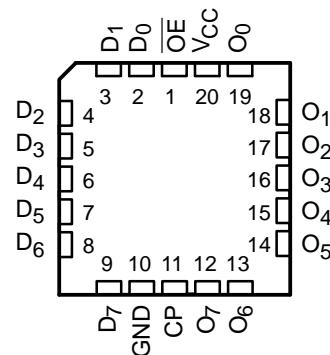


- Function, Pinout, and Drive Compatible With FCT and F Logic
- Reduced  $V_{OH}$  (Typically = 3.3 V) Versions of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- $I_{off}$  Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- Fully Compatible With TTL Input and Output Logic Levels
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)
- Edge-Triggered D-Type Inputs
- 250-MHz Typical Switching Rate
- CY54FCT574T
  - 32-mA Output Sink Current
  - 12-mA Output Source Current
- CY74FCT574T
  - 64-mA Output Sink Current
  - 32-mA Output Source Current
- 3-State Outputs

**CY54FCT574T . . . D PACKAGE**  
**CY74FCT574T . . . Q OR SO PACKAGE**  
**(TOP VIEW)**



**CY54FCT574T . . . L PACKAGE**  
**(TOP VIEW)**



## description

The 'FCT574T devices are high-speed, low-power, octal D-type flip-flops, featuring separate D-type inputs for each flip-flop. These devices have 3-state outputs for bus-oriented applications. A buffered clock (CP) and output-enable ( $\overline{OE}$ ) inputs are common to all flip-flops. The 'FCT574T are identical to 'FCT374T, except for a flow-through pinout to simplify board design. The eight flip-flops in the 'FCT574T store the state of their individual D inputs that meet the setup-time and hold-time requirements on the low-to-high CP transition. When  $\overline{OE}$  is low, the contents of the eight flip-flops are available at the outputs. When  $\overline{OE}$  is high, the outputs are in the high-impedance state. The state of  $\overline{OE}$  does not affect the state of the flip-flops.

These devices are fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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 On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

**CY54FCT574T, CY74FCT574T  
8-BIT REGISTERS  
WITH 3-STATE OUTPUTS**

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**ORDERING INFORMATION**

TA	PACKAGE <sup>†</sup>		SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	QSOP – Q	Tape and reel	5.2	CY74FCT574CTQCT	FCT574C
	SOIC – SO	Tube	5.2	CY74FCT574CTSOC	FCT574C
		Tape and reel	5.2	CY74FCT574CTSOCT	
	QSOP – Q	Tape and reel	6.5	CY74FCT574ATQCT	FCT574A
	SOIC – SO	Tube	6.5	CY74FCT574ATSOC	FCT574A
		Tape and reel	6.5	CY74FCT574ATSOCT	
-55°C to 125°C	QSOP – Q	Tape and reel	10	CY74FCT574TQCT	FCT574
	SOIC – SO	Tube	10	CY74FCT574TSOC	FCT574
		Tape and reel	10	CY74FCT574TSOCT	
	CDIP – D	Tube	6.2	CY54FCT574CTDMB	
	CDIP – D	Tube	7.2	CY54FCT574ATDMB	
	LCC – L	Tube	7.2	CY54FCT574ATLMB	

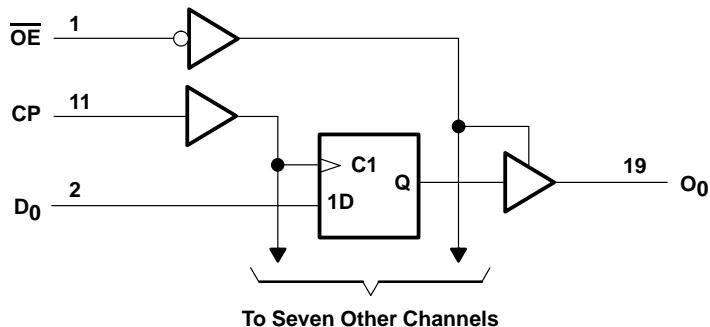
<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).

**FUNCTION TABLE**

INPUTS			OUTPUT
D	CP	OE	O
H	↑	L	H
L	↑	L	L
X	X	H	Z

H = High logic level, L = Low logic level,  
X = Don't care, Z = High-impedance state,  
↑ = Low-to-high clock transition

**logic diagram (positive logic)**



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range to ground potential	.....	-0.5 V to 7 V
DC input voltage range	.....	-0.5 V to 7 V
DC output voltage range	.....	-0.5 V to 7 V
DC output current (maximum sink current/pin)	.....	120 mA
Package thermal impedance, $\theta_{JA}$ (see Note 1): Q package	.....	68°C/W
	SO package	58°C/W
Ambient temperature range with power applied, $T_A$	.....	-65°C to 135°C
Storage temperature range, $T_{stg}$	.....	-65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

#### **recommended operating conditions (see Note 2)**

		CY54FCT574T			CY74FCT574T			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V <sub>CC</sub>	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V <sub>IH</sub>	High-level input voltage		2		2			V
V <sub>IL</sub>	Low-level input voltage			0.8			0.8	V
I <sub>OH</sub>	High-level output current			-12			-32	mA
I <sub>OL</sub>	Low-level output current			32			64	mA
T <sub>A</sub>	Operating free-air temperature	-55		125	-40		85	°C

**NOTE 2:** All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation.

**CY54FCT574T, CY74FCT574T  
8-BIT REGISTERS  
WITH 3-STATE OUTPUTS**

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**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	CY54FCT574T			CY74FCT574T			UNIT
		MIN	TYP†	MAX	MIN	TYP†	MAX	
V <sub>IK</sub>	V <sub>CC</sub> = 4.5 V, I <sub>IN</sub> = -18 mA		-0.7	-1.2				V
	V <sub>CC</sub> = 4.75 V, I <sub>IN</sub> = -18 mA				-0.7	-1.2		
V <sub>OH</sub>	V <sub>CC</sub> = 4.5 V, I <sub>OH</sub> = -12 mA	2.4	3.3					V
	V <sub>CC</sub> = 4.75 V	I <sub>OH</sub> = -32 mA			2			
		I <sub>OH</sub> = -15 mA			2.4	3.3		
V <sub>OL</sub>	V <sub>CC</sub> = 4.5 V, I <sub>OL</sub> = 32 mA	0.3	0.55					V
	V <sub>CC</sub> = 4.75 V, I <sub>OL</sub> = 64 mA				0.3	0.55		
V <sub>hys</sub>	All inputs	0.2			0.2			V
I <sub>I</sub>	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = V <sub>CC</sub>		5					μA
	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> = V <sub>CC</sub>						5	
I <sub>IH</sub>	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 2.7 V		±1					μA
	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> = 2.7 V						±1	
I <sub>IL</sub>	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 0.5 V		±1					μA
	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> = 0.5 V						±1	
I <sub>off</sub>	V <sub>CC</sub> = 0 V, V <sub>OUT</sub> = 4.5 V		±1				±1	μA
I <sub>OS</sub> ‡	V <sub>CC</sub> = 5.5 V, V <sub>OUT</sub> = 0 V	-60	-120	-225				mA
	V <sub>CC</sub> = 5.25 V, V <sub>OUT</sub> = 0 V				-60	-120	-225	
I <sub>OZH</sub>	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 2.7 V		10					μA
	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> = 2.7 V						10	
I <sub>OZL</sub>	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 0.5 V		-10					μA
	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> = 0.5 V						-10	
I <sub>CC</sub>	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> ≤ 0.2 V, V <sub>IN</sub> ≥ V <sub>CC</sub> - 0.2 V	0.1	0.2					mA
	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> ≤ 0.2 V, V <sub>IN</sub> ≥ V <sub>CC</sub> - 0.2 V				0.1	0.2		
ΔI <sub>CC</sub>	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 3.4 V§, f <sub>1</sub> = 0, Outputs open	0.5	2					mA
	V <sub>CC</sub> = 5.25 V, V <sub>IN</sub> = 3.4 V§, f <sub>1</sub> = 0, Outputs open				0.5	2		

† Typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C.

‡ Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, I<sub>OS</sub> tests should be performed last.

§ Per TTL-driven input (V<sub>IN</sub> = 3.4 V); all other inputs at V<sub>CC</sub> or GND

**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)**

PARAMETER	TEST CONDITIONS	CY54FCT574T			CY74FCT574T			UNIT	
		MIN	TYP <sup>†</sup>	MAX	MIN	TYP <sup>†</sup>	MAX		
I <sub>CCD</sub> <sup>¶</sup>	V <sub>CC</sub> = 5.5 V, Outputs open, One bit switching at 50% duty cycle, $\overline{OE}$ = GND, $V_{IN} \leq 0.2$ V or $V_{IN} \geq V_{CC} - 0.2$ V	0.06 0.12			0.06 0.12			mA/ MHz	
	V <sub>CC</sub> = 5.25 V, Outputs open, One bit switching at 50% duty cycle, $\overline{OE}$ = GND, $V_{IN} \leq 0.2$ V or $V_{IN} \geq V_{CC} - 0.2$ V								
I <sub>C</sub>	V <sub>CC</sub> = 5.5 V, $f_0 = 10$ MHz, Outputs open, $OE = GND$	One bit switching at $f_1 = 5$ MHz at 50% duty cycle	$V_{IN} \leq 0.2$ V or $V_{IN} \geq V_{CC} - 0.2$ V	0.7 1.4					
			$V_{IN} = 3.4$ V or GND	1.2 3.4					
		Eight bits switching at $f_1 = 2.5$ MHz at 50% duty cycle	$V_{IN} \leq 0.2$ V or $V_{IN} \geq V_{CC} - 0.2$ V	1.6 3.2 <sup>  </sup>					
			$V_{IN} = 3.4$ V or GND	3.9 12.2 <sup>  </sup>					
	V <sub>CC</sub> = 5.25 V, $f_0 = 10$ MHz, Outputs open, $OE = GND$	One bit switching at $f_1 = 5$ MHz at 50% duty cycle	$V_{IN} \leq 0.2$ V or $V_{IN} \geq V_{CC} - 0.2$ V			0.7 1.4		mA	
			$V_{IN} = 3.4$ V or GND			1.2 3.4			
		Eight bits switching at $f_1 = 2.5$ MHz at 50% duty cycle	$V_{IN} \leq 0.2$ V or $V_{IN} \geq V_{CC} - 0.2$ V			1.6 3.2 <sup>  </sup>			
			$V_{IN} = 3.4$ V or GND			3.9 12.2 <sup>  </sup>			
C <sub>i</sub>				5	10	5	10	pF	
C <sub>o</sub>				9	12	9	12	pF	

<sup>†</sup> Typical values are at  $V_{CC} = 5$  V,  $T_A = 25^\circ\text{C}$ .

<sup>¶</sup> This parameter is derived for use in total power-supply calculations.

$$\# I_C = I_{CC} + \Delta I_{CC} \times D_H \times N_T + I_{CCD} (f_0/2 + f_1 \times N_1)$$

Where:

I<sub>C</sub> = Total supply current

I<sub>CC</sub> = Power-supply current with CMOS input levels

$\Delta I_{CC}$  = Power-supply current for a TTL high input ( $V_{IN} = 3.4$  V)

D<sub>H</sub> = Duty cycle for TTL inputs high

N<sub>T</sub> = Number of TTL inputs at D<sub>H</sub>

I<sub>CCD</sub> = Dynamic current caused by an input transition pair (HLH or LHL)

f<sub>0</sub> = Clock frequency for registered devices, otherwise zero

f<sub>1</sub> = Input signal frequency

N<sub>1</sub> = Number of inputs changing at f<sub>1</sub>

All currents are in milliamperes and all frequencies are in megahertz.

<sup>||</sup> Values for these conditions are examples of the I<sub>CC</sub> formula.

**CY54FCT574T, CY74FCT574T  
8-BIT REGISTERS  
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**timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)**

		CY54FCT574T		CY54FCT574AT		CY54FCT574CT		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
$t_W$	Pulse duration, CP high or low	7		6		6		ns
$t_{SU}$	Setup time, data before CP↑	2		2		2		ns
$t_h$	Hold time, data after CP↑	1.5		1.5		1.5		ns

**timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)**

		CY74FCT574T		CY74FCT574AT		CY74FCT574CT		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
$t_W$	Pulse duration, CP high or low	7		5		5		ns
$t_{SU}$	Setup time, data before CP↑	2		2		2		ns
$t_h$	Hold time, data after CP↑	1.5		1.5		1.5		ns

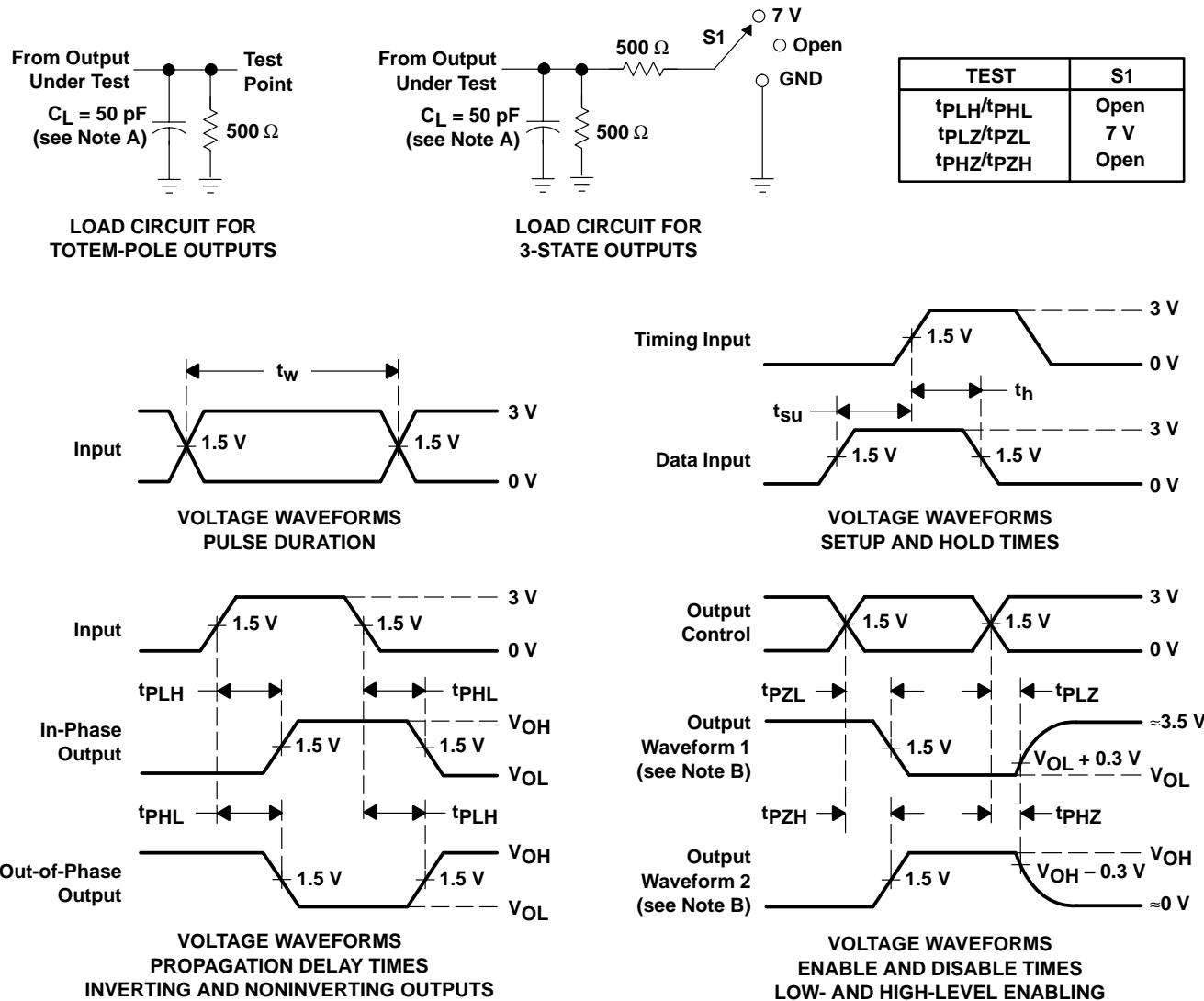
**switching characteristics over operating free-air temperature range (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	CY54FCT574T		CY54FCT574AT		CY54FCT574CT		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
$t_{PLH}$	CP	O	2	11	2	7.2	2	6.2	ns
$t_{PHL}$			2	11	2	7.2	2	6.2	
$t_{PZH}$	$\overline{OE}$	O	1.5	14	1.5	7.5	1.5	6.2	ns
$t_{PZL}$			1.5	14	1.5	7.5	1.5	6.2	
$t_{PHZ}$	$\overline{OE}$	O	1.5	8	1.5	6.5	1.5	5.7	ns
$t_{PLZ}$			1.5	8	1.5	6.5	1.5	5.7	

**switching characteristics over operating free-air temperature range (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	CY74FCT574T		CY74FCT574AT		CY74FCT574CT		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
$t_{PLH}$	CP	O	2	10	2	6.5	2	5.2	ns
$t_{PHL}$			2	10	2	6.5	2	5.2	
$t_{PZH}$	$\overline{OE}$	O	1.5	12.5	1.5	6.5	1.5	5.5	ns
$t_{PZL}$			1.5	12.5	1.5	6.5	1.5	5.5	
$t_{PHZ}$	$\overline{OE}$	O	1.5	8	1.5	5.5	1.5	5	ns
$t_{PLZ}$			1.5	8	1.5	5.5	1.5	5	

## PARAMETER MEASUREMENT INFORMATION



**Figure 1** Load Circuit and Voltage Waveforms

NOTES: A.  $C_L$  includes probe and jig capacitance.  
 B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.  
 C. The outputs are measured one at a time with one input transition per measurement.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9222203M2A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9222203M2A CY54FCT 574ATLMB	<span style="background-color: red; color: white; padding: 2px;">Samples</span>
5962-9222203MRA	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9222203MR A	<span style="background-color: red; color: white; padding: 2px;">Samples</span>
5962-9222205MRA	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9222205MR A	<span style="background-color: red; color: white; padding: 2px;">Samples</span>
CY54FCT574ATLMB	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9222203M2A CY54FCT 574ATLMB	<span style="background-color: red; color: white; padding: 2px;">Samples</span>
CY74FCT574ATQCT	ACTIVE	SSOP	DBQ	20	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT574A	<span style="background-color: red; color: white; padding: 2px;">Samples</span>
CY74FCT574ATSOC	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT574A	<span style="background-color: red; color: white; padding: 2px;">Samples</span>
CY74FCT574CTQCT	ACTIVE	SSOP	DBQ	20	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT574C	<span style="background-color: red; color: white; padding: 2px;">Samples</span>
CY74FCT574CTSOC	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT574C	<span style="background-color: red; color: white; padding: 2px;">Samples</span>
CY74FCT574TQCT	ACTIVE	SSOP	DBQ	20	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT574	<span style="background-color: red; color: white; padding: 2px;">Samples</span>
CY74FCT574TQCTG4	ACTIVE	SSOP	DBQ	20	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT574	<span style="background-color: red; color: white; padding: 2px;">Samples</span>
CY74FCT574TSOC	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT574	<span style="background-color: red; color: white; padding: 2px;">Samples</span>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

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**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

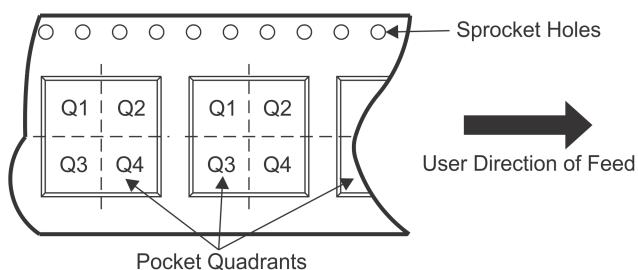
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**TAPE AND REEL INFORMATION**
**REEL DIMENSIONS**

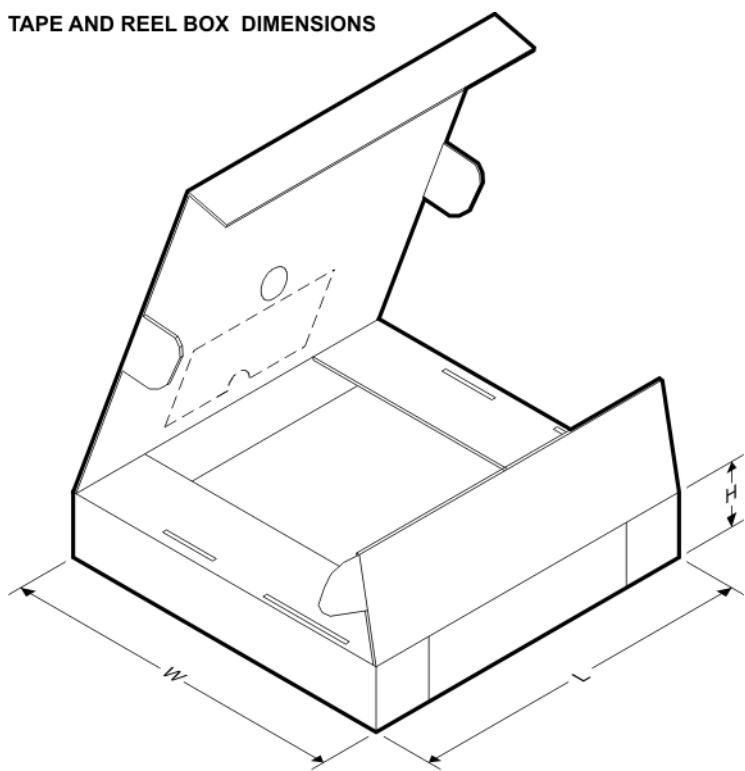
**TAPE DIMENSIONS**


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


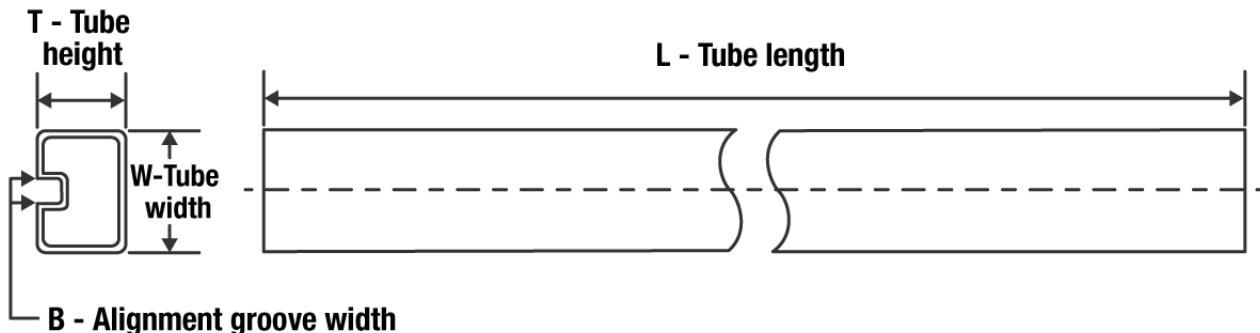
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT574ATQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT574CTQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT574TQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT574ATQCT	SSOP	DBQ	20	2500	853.0	449.0	35.0
CY74FCT574CTQCT	SSOP	DBQ	20	2500	853.0	449.0	35.0
CY74FCT574TQCT	SSOP	DBQ	20	2500	853.0	449.0	35.0

**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
5962-9222203M2A	FK	LCCC	20	1	506.98	12.06	2030	NA
CY54FCT574ATLMB	FK	LCCC	20	1	506.98	12.06	2030	NA
CY74FCT574ATSOC	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT574CTSOC	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT574TSOC	DW	SOIC	20	25	507	12.83	5080	6.6

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